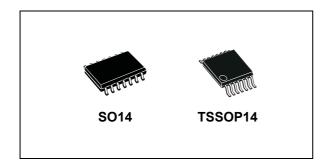


Quad 2-input Schmitt NAND gate

Datasheet - production data



Features

- High-speed: t_{PD} = 11 ns (typ.) at V_{CC} = 6 V
- Low power dissipation:
 I_{CC} = 1 μA (max.) at T_A = 25 °C
- High noise immunity:
 V_H(typ) = 0.9 V at V_{CC} = 5 V
- Symmetrical output impedance: |I_{OH}| = I_{OL} = 4 mA (min.)
- Balanced propagation delays: $t_{PLH} \cong t_{PHL}$

- Wide operating voltage range:
 V_{CC} (opr) = 2 V to 6 V
- Pin and function compatible with 74 series 132
- ESD performance

HBM: 2 kVMM: 200 VCDM: 1 kV

Description

The M74HC132 is a high-speed CMOS quad 2-input Schmitt NAND gate fabricated with silicon gate C²MOS technology.

Pin configuration and function are identical to those of the M74HC00. The hysteresis characteristics (around 20 % V_{CC}) of all inputs allow slowly changing input signals to be transformed into sharply defined jitter-free output signals.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

Table 1. Device summary

Order code	Temp. range	Package	Packing	Marking
M74HC132RM13TR	-55 °C to 125 °C	S014		74HC132
M74HC132YRM13TR ⁽¹⁾	-40 °C to 125 °C	SO14 (automotive grade)	Tape and reel	74HC132Y
M74HC132TTR	-55 °C to 125 °C	TSSOP14	rape and reer	HC132
M74HC132YTTR ⁽¹⁾	-40 °C to 125 °C	TSSOP14 (automotive grade)		HC132Y

Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

Contents M74HC132

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1	Pin information
2	Functional description
3	Electrical characteristics
4	Package information
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	4.2 TSSOP14 package information
5	Ordering information
6	Revision history

M74HC132 Pin information

1 Pin information

Figure 1. Pin connection and IED logic symbols

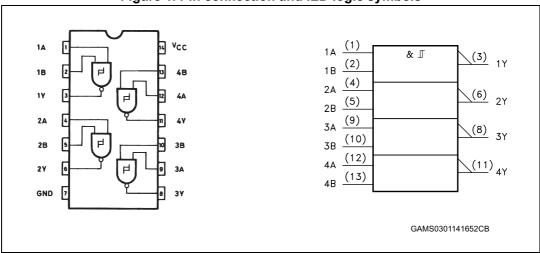


Table 2. Pin description

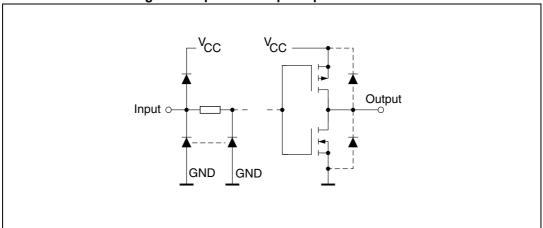
		· ·
Pin no	Symbol	Name and function
1, 4, 9, 12	1A to 4A	Data inputs
2, 5, 10, 13	1B to 4B	Data inputs
3, 6, 8, 11	1Y to 4Y	Data outputs
7	GND	Ground (0 V)
14	V _{CC}	Positive supply voltage

2 Functional description

Table 3. Truth table

Α	В	Υ
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

Figure 2. Input and output equivalent circuit



3 Electrical characteristics

"Absolute maximum ratings" are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

Table 4. Absolute maximum ratings

Symbol	Parameter	Value	Unit	
V _{CC}	Supply voltage	-0.5 to +7		
VI	DC input voltage		-0.5 to V _{CC} + 0.5	V
V _O	DC output voltage		-0.5 to VCC + 0.5	
I _{IK}	DC input diode current		±20	
I _{OK}	DC output diode current		±20	
I _O	DC output current		±25	mA
I _{CC} or I _{GND}	DC V _{CC} or ground current		±50	
D	Dower dissination	SO14	500 ⁽¹⁾	mW
P _D	Power dissipation	450 ⁽¹⁾	11100	
T _{stg}	Storage temperature	-65 to +150	°C	
T _L	Lead temperature (10 sec)		300	

^{1.} Power dissipation at 65 °C. Derating from 65 °C to 125 °C: SO14 -7 mW/°C, TSSOP14 -6.1 mW/°C.

Table 5. Recommended operating conditions

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	2 to 6	
VI	Input voltage	0 to V _{CC}	V
V _O	Output voltage	0 10 VCC	
T _{op}	Operating temperature	-55 to 125	°C

Electrical characteristics M74HC132

Table 6. DC specifications

		7	Test condition				Value	ļ			
Symbol	Parameter	V _{cc}		Т,	₄ = 25 °	,C	-40 to	85 °C	-55 to	125 °C	Unit
	(V)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	•	
		2.0		1.0	1.25	1.5	1.0	1.5	1.0	1.5	
V_{P}	High level threshold voltage	4.5		2.3	2.7	3.15	2.3	3.15	2.3	3.15	V
		6.0		3.0	3.5	4.2	3.0	4.2	3.0	4.2	
		2.0		0.3	0.65	0.9	0.3	0.9	0.3	0.9	
V_N	Low level threshold voltage	4.5		1.13	1.6	2.0	1.13	2.0	1.13	2.0	V
		6.0		1.5	2.3	2.6	1.5	2.6	1.5	2.6	
		2.0		0.3	0.6	1.0	0.3	1.0	0.3	1.0	
V_{H}	Hysteresis voltage	4.5		0.6	1.1	1.4	0.6	1.4	0.6	1.4	V
		6.0		0.8	1.2	1.4	0.8	1.7	0.8	1.7	
		2.0	I _O = -20 μA	1.9	2.0		1.9		1.9		
		4.5	I _O = -20 μA	4.4	4.5		4.4		4.4		
V _{OH}	High level output voltage	6.0	I _O = -20 μA	5.9	6.0		5.9		5.9		V
		4.5	$I_{O} = -4.0 \text{ mA}$	4.18	4.31		4.13		4.10		
		6.0	$I_{O} = -5.2 \text{ mA}$	5.68	5.8		5.63		5.60		
		2.0	I _O = -20 μA			0.1		0.1		0.1	
		4.5	I _O = -20 μA			0.1		0.1		0.1	
V_{OL}	Low level output voltage	6.0	I _O = -20 μA			0.1		0.1		0.1	V
	, onage	4.5	$I_{O} = -4.0 \text{ mA}$		0.17	0.26		0.33		0.40	
		6.0	$I_{O} = -5.2 \text{ mA}$		0.18	0.26		0.33		0.40	
I _I	Input leakage current	6.0	V _I = V _{CC} or GND			±0.1		±1		±1	μА
I _{CC}	Quiescent supply current	6.0	V _I = V _{CC} or GND			1		10		20	μА

Table 7. AC electrical characteristics ($C_1 = 50$ pF, Input $t_r = t_f = 6$ ns)

		Test condition		Value						
Symbol	bol Parameter			T _A = 25 °C		-40 to 85 °C		-55 to 125 °C		Unit
	V _{CC} (V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.		
		2.0		30	75		95		110	
t _{TLH} , t _{THL}	Output transition time	4.5	8	15		19		22	ns	
		6.0		7	13		16		19	
		2.0	_	52	105	_	130	-	160	
t _{PLH} , t _{PHL}	Propagation delay time	4.5		13	21		26		32	ns
		6.0		11	18		22		27	

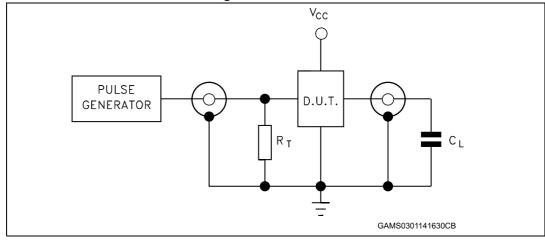
Table 8. Capacitive characteristics

		Test condition		Value							
Sym	Parameter	V 00	Т	A = 25°	С	-40 to	85 °C	-55 to	125 °C	Unit	
		V _{CC} (V)	Min	Тур	Max	Min	Max	Min	Max		
C _{IN}	Input capacitance			5	10		10		10		
C _{PD}	Power dissipation capacitance ⁽¹⁾	5.0	-	29		-		-		pF	

C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load (refer to test circuit). Average operating current can be obtained by the following equation:

I_{CC(opr)} = C_{PD} x V_{CC} x f_{IN} + I_{CC}/4 (per gate).

Figure 3. Test circuit



1. Legend: $C_L = 50$ pF or equivalent (includes jig and probe capacitance). $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω).

Electrical characteristics M74HC132

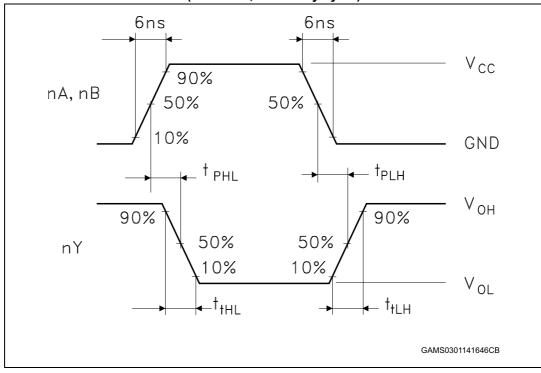


Figure 4. Propagation delay times (f = 1 MHz; 50 % duty cycle)



M74HC132 Package information

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.



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Package information M74HC132

4.1 SO14 package information

Figure 5. SO14 package mechanical drawing

Table 9. SO14 package mechanical data

			Dime:	nsions		
Ref		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
С		0.5			0.019	
c1		45 °			45 °	
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
е		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
М			0.68			0.026
S			8 °			8 °

M74HC132 Package information

4.2 TSSOP14 package information

Figure 6. TSSOP14 package mechanical drawing

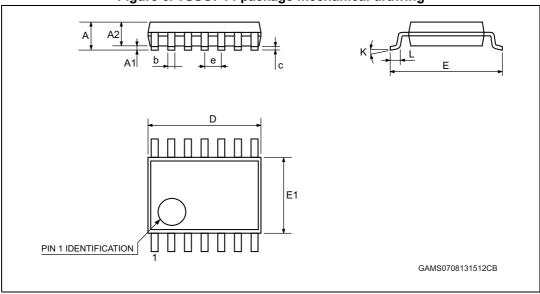


Table 10. TSSOP14 package mechanical data

	Dimensions							
Ref		Millimeters						
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α			1.2			0.047		
A1	0.05		0.15	0.002	0.004	0.006		
A2	0.8	1	1.05	0.031	0.039	0.041		
b	0.19		0.30	0.007		0.012		
С	0.09		0.20	0.004		0.0089		
D	4.9	5	5.1	0.193	0.197	0.201		
E	6.2	6.4	6.6	0.244	0.252	0.260		
E1	4.3	4.4	4.48	0.169	0.173	0.176		
е		0.65			0.0256			
K	0 °		8 °	0 °		8°		
L	0.45	0.60	0.75	0.018	0.024	0.030		

Ordering information M74HC132

5 Ordering information

Table 11. Order codes

Order code	Temp. range	Package	Packing	Marking
M74HC132RM13TR	-55 °C to 125 °C	S014		74HC132
M74HC132YRM13TR ⁽¹⁾	-40 °C to 125 °C	SO14 (automotive grade)	Tape and reel	74HC132Y
M74HC132TTR	-55 °C to 125 °C	TSSOP14	rape and reer	HC132
M74HC132YTTR ⁽¹⁾	-40 °C to 125 °C	TSSOP14 (automotive grade)		HC132Y

Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

6 Revision history

Table 12. Document revision history

Date	Revision	Changes
10-Jan-2014	3	Removed DIP14 package Added ESD data to <i>Features Table 1: Device summary</i> : added automotive grade order codes, added temperature range and marking details. Added <i>Section 5: Ordering information</i> .

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